

/ Descriptions

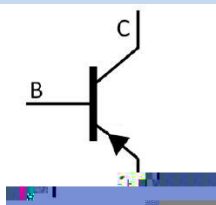
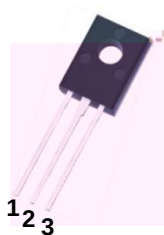
WR0459I SQS Silicon PNP transistor in a TO-126F Plastic Package.

/ Features

5VG99<+D,
Complementary pair with 2SD669(A).

/ Applications

Low frequency power amplifier.

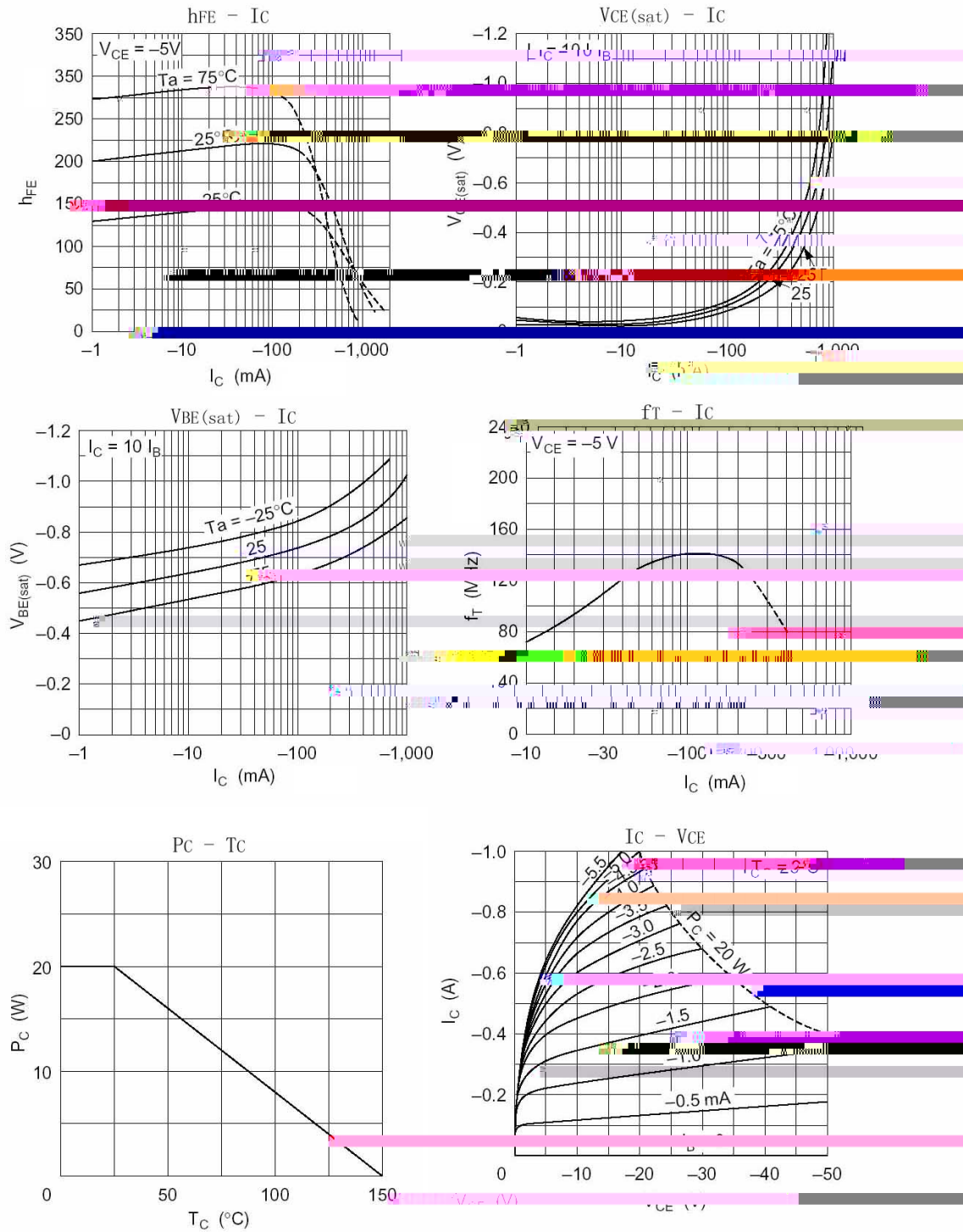
/ Equivalent Circuit**/ Pinning**

PIN1 Emitter PIN 2 Collector PIN 3 Base

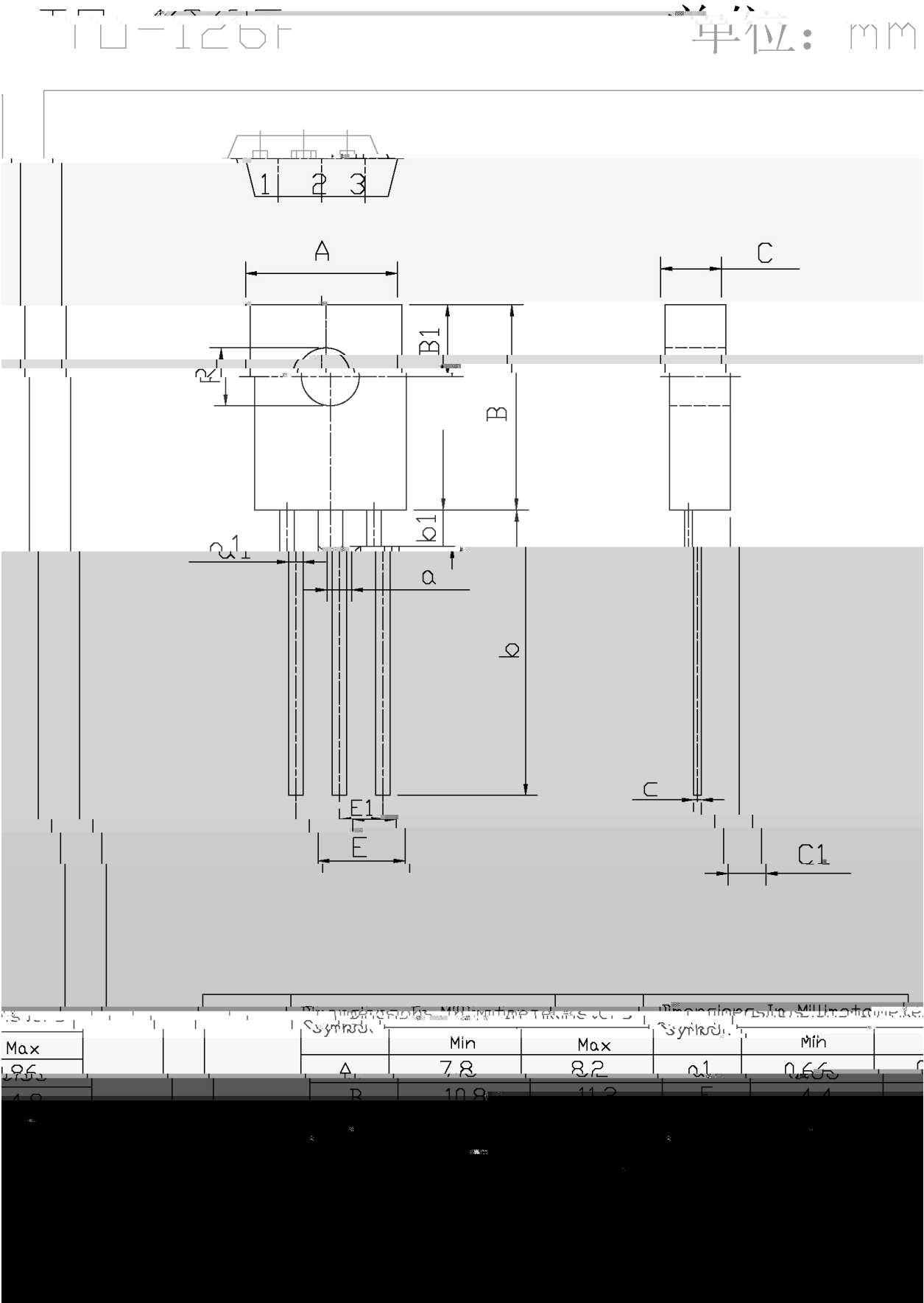
/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	B	C	D
h_{FE} Range	60 120	100 200	160 320

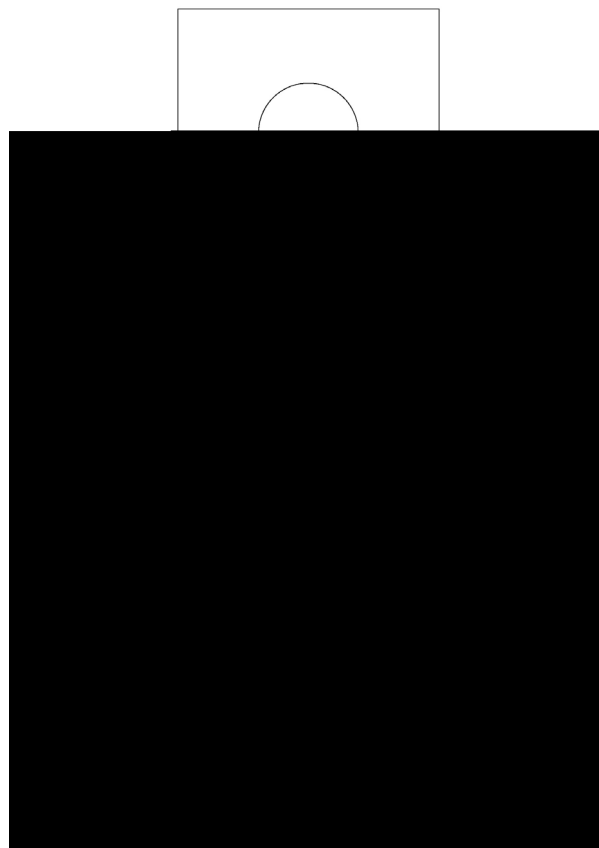
/ Electrical Characteristic Curve



/ Package Dimensions



/ Marking Instructions



EU

E97<

E= k_{IH}

Note:

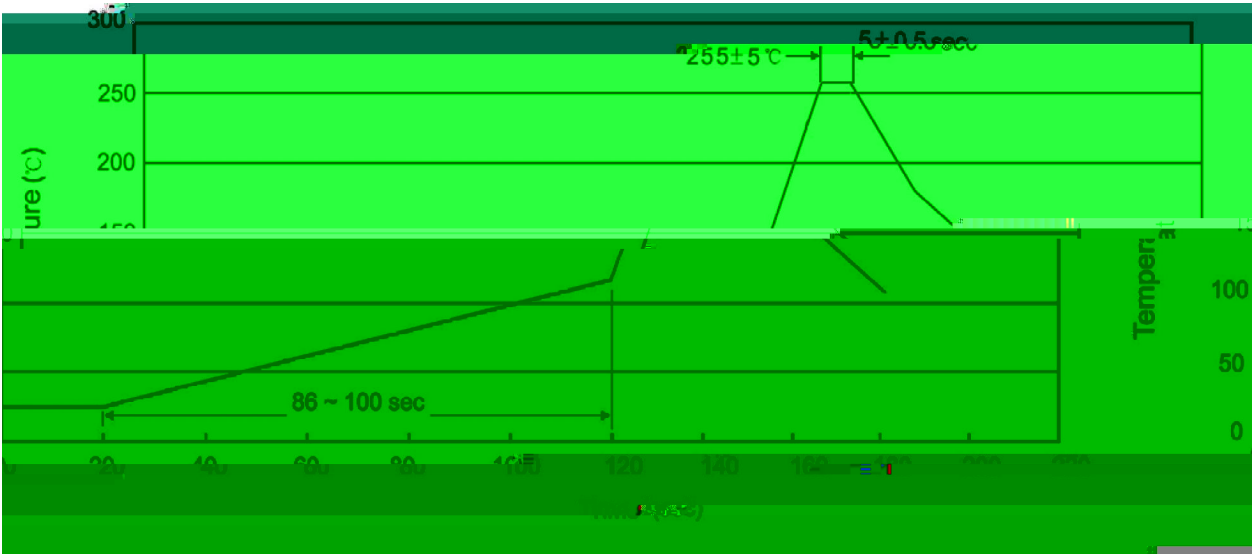
BR: Company Code

B649 : Product Type.

B: h_{FE} Classifications Symbol

***: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



- Note:
1. Preheating: 25~150℃, Time: 60~90sec.

2. Peak Temp.: 255 ± 5℃, Duration: 5 ± 0.5sec.

3. Cooling Speed: 2~10℃/sec.

5	2	E	255 ± 5
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